Vishay General Semiconductor

Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.50$ V at $I_F = 5$ A

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- · Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	VB60170G	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	170	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	60	٨	
	per diode		30	- A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I _{FSM}	210	A	
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +175	°C	



TMBS[®]

PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 30 A					
V _{RRM}	170 V					
I _{FSM}	210 A					
V _F at I _F = 30 A	0.72 V					
T _J max.	175 °C					
Package	TO-263AB					
Diode variations	Common cathode					

RoHS COMPLIANT





HEATSINK



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F (1)	0.65	-	V	
	I _F = 15 A			0.78	-		
	I _F = 30 A			0.87	1.02		
	$I_F = 5 A$	T _A = 125 °C		0.50	-		
	I _F = 15 A			0.62	-		
	I _F = 30 A			0.72	0.80		
Reverse current per diode	V _R = 136 V	T _A = 25 °C	I _R (2)	1.5	-	μA	
		T _A = 125 °C		2.5	-	mA	
	V _R = 170 V	T _A = 25 °C		-	450	μA	
		T _A = 125 °C		5	50	mA	

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

 $^{(2)}$ Pulse test: Pulse width $\leq 20\ ms$

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	VB60170G	UNIT	
Typical thermal resistance	per diode	$R_{ ext{ heta}JC}$	1.0	°C/W	
	per device		0.7	0/10	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-263AB	VB60170G-E3/4W	1.38	4W	50/tube	Tube
TO-263AB	VB60170G-E3/8W	1.38	8W	800/reel	Tape and reel

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

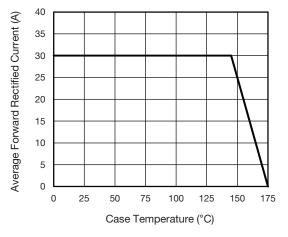


Fig. 1 - Maximum Forward Current Derating Curve

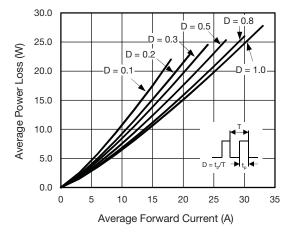


Fig. 2 - Forward Power Loss Characteristics Per Diode

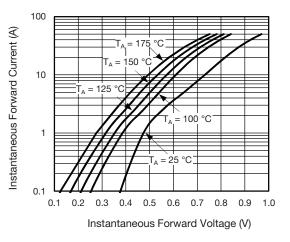
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Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

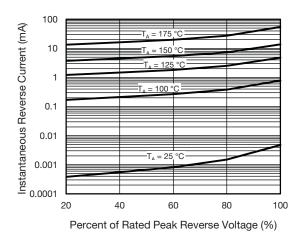


Fig. 4 - Typical Reverse Characteristics Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

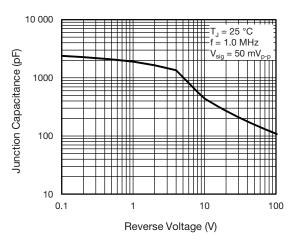
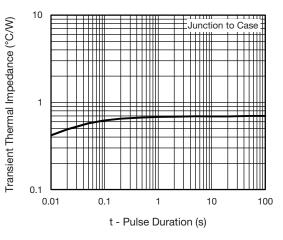
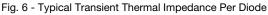
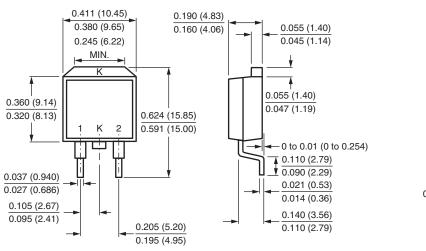


Fig. 5 - Typical Junction Capacitance Per Diode

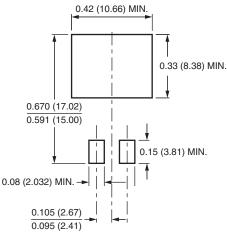






TO-263AB

Mounting Pad Layout



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